

查询HMC-ALH369供应商



v00.1007

捷多邦，专业PCB打样工厂，24小时加急出货

# HMC-ALH369

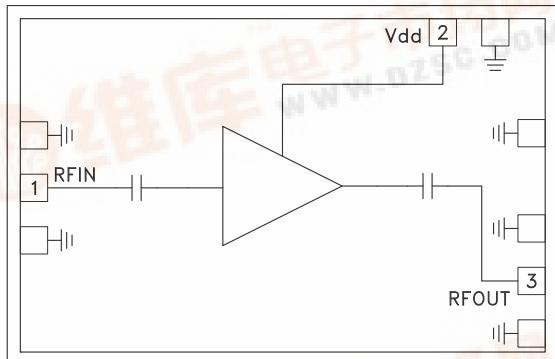
## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 24 - 40 GHz

### Typical Applications

This HMC-ALH369 is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- Phased Arrays
- VSAT
- SATCOM

### Functional Diagram



### Electrical Specifications<sup>[1]</sup>, $T_A = +25^\circ C$ , $Vdd = +5V$ , $Idd = 66mA$

Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range		24 - 32			32 - 40		GHz
Gain	20	22		15	17		dB
Noise Figure		2	2.5		2.1	2.5	dB
Input Return Loss		12			8		dB
Output Return Loss		12			12		dB
Output Power for 1 dB Compression	9	11		9	11		dBm
Supply Current (Idd)		66			66		mA

[1] Unless otherwise indicated, all measurements are from probed die

### Features

Excellent Noise Figure: 2.0 dB

Gain: 22 dB

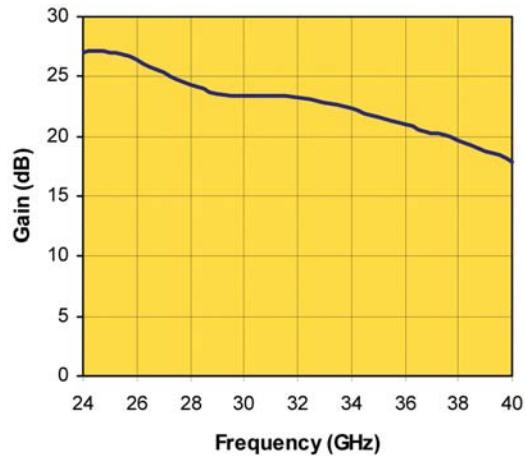
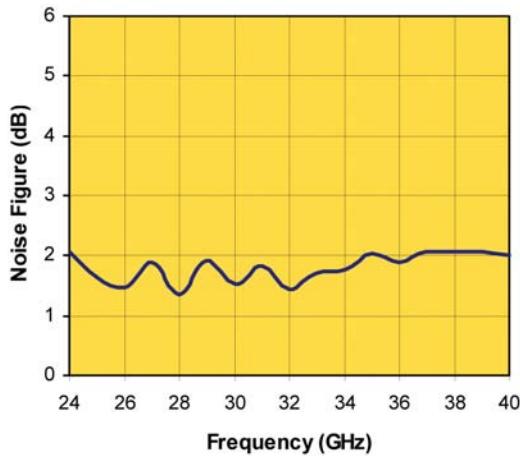
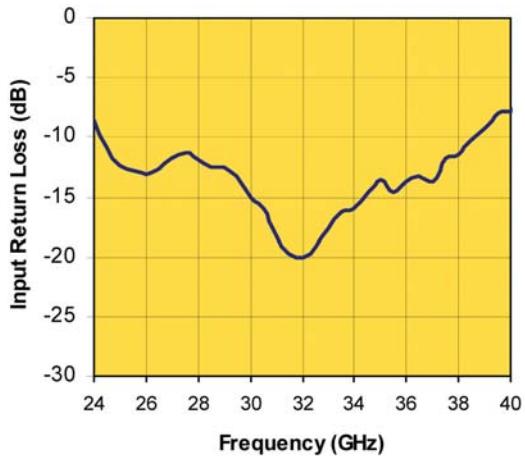
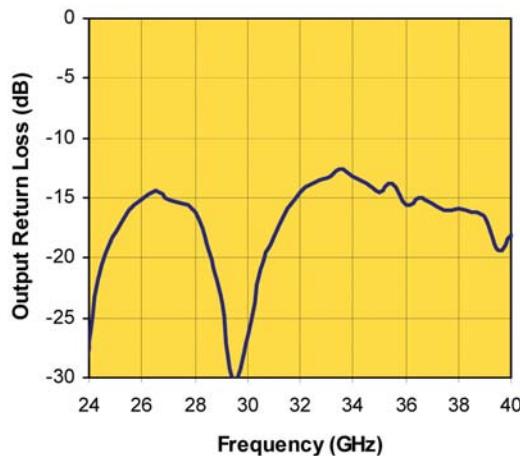
P1dB Output Power: +11 dBm

Supply Voltage: +5V @ 66 mA

Die Size: 2.10 x 1.37 x 0.1 mm

### General Description

The HMC-ALH369 is a GaAs MMIC HEMT three stage, self-biased Low Noise Amplifier die which operates between 24 and 40 GHz. The amplifier provides 22 dB of gain, from a single bias supply of +5V @ 66 mA with a noise figure of 2 dB. The HMC-ALH369 amplifier die is ideal for integration into Multi-Chip-Modules (MCMs) due to its small size (2.88 mm<sup>2</sup>).

**GaAs HEMT MMIC LOW NOISE  
AMPLIFIER, 24 - 40 GHz**
**Linear Gain vs. Frequency****Noise Figure vs. Frequency****Input Return Loss vs. Frequency****Output Return Loss vs. Frequency**

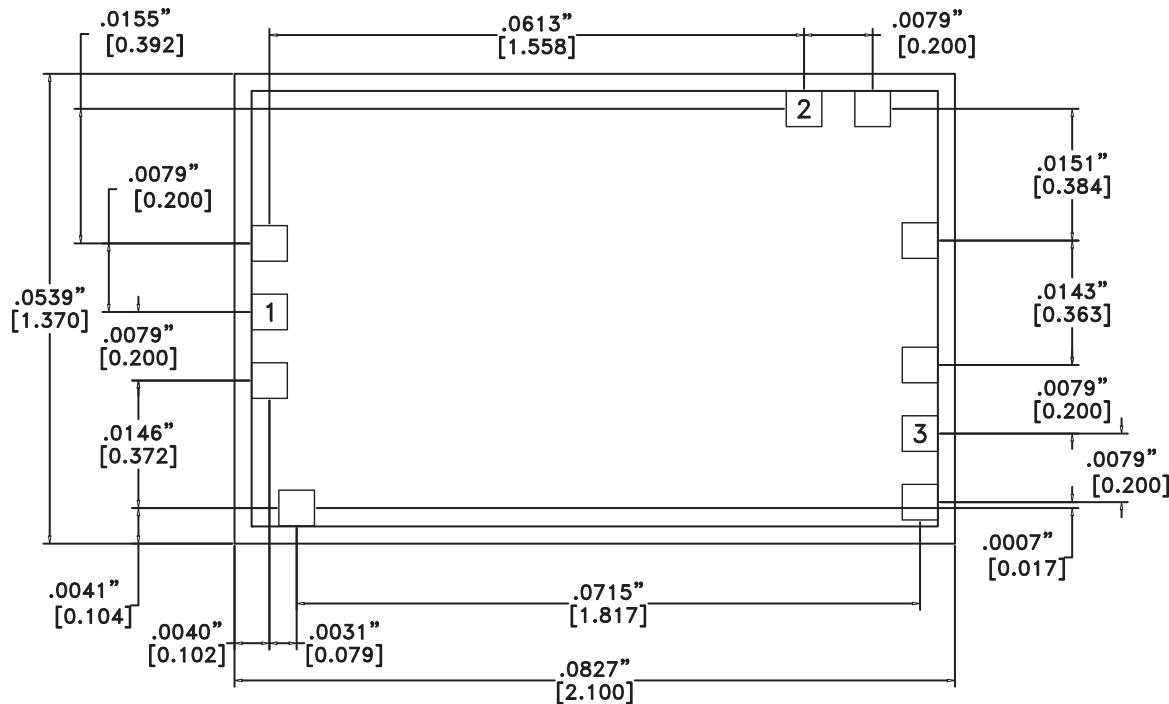
Note: Measured Performance Characteristics (Typical Performance at 25°C) Vd= 5V, Id = 66 mA

For price, delivery, and to place orders, please contact Hittite Microwave Corporation:

**GaAs HEMT MMIC LOW NOISE  
AMPLIFIER, 24 - 40 GHz**
**Absolute Maximum Ratings**

Drain Bias Voltage	+5.5 Vdc
RF Input Power (24 - 32 GHz)	5 dBm
RF Input Power (32 - 40 GHz)	-1 dBm
Channel Temperature	180 °C
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C


 ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

**Outline Drawing**


## NOTES:

1. ALL DIMENSIONS ARE IN INCHES [MM].
2. TYPICAL BOND PAD IS .004" SQUARE.
3. BACKSIDE METALLIZATION: GOLD.
4. BACKSIDE METAL IS GROUND.
5. BOND PAD METALLIZATION: GOLD.
6. CONNECTION NOT REQUIRED FOR UNLABELED BOND PADS.
7. OVERALL DIE SIZE ±.002"